

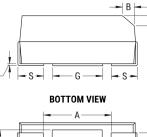
T493A474K035AT6110

T493 HRA, Tantalum, MnO2 Tantalum, HRA, .47 uF, 10%, 35 VDC, SMD, MnO2, Molded, High Reliability, N/A, 14 Ohms, 3216, Height Max = 1.8mm

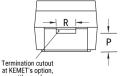
CATHODE (-) END VIEW

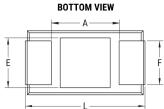


ANODE (+) END VIEW



SIDE VIEW





d	t KEMETS Option,	
	either end	

Click here for the 3D model.

Dimensions	
Footprint	3216
L	3.2mm +/-0.2mm
W	1.6mm +/-0.2mm
Н	1.6mm +/-0.2mm
Т	0.13mm REF
S	0.8mm +/-0.3mm
F	1.2mm +/-0.1mm
А	1.2mm MIN
В	0.4mm +/-0.15mm
E	1.3mm REF
G	1.1mm REF
Р	0.35mm MIN
R	0.4mm REF
Х	0.1mm +/-0.1mm

Т

Packaging Specifications		
Packaging	T&R, 178mm	
Packaging Quantity	2000	

General Information			
Series	T493 HRA		
Dielectric	MnO2 Tantalum		
Style	SMD Chip		
Description	SMD, MnO2, Molded, High Reliability		
Features	High Reliability		
RoHS	Yes		
Termination	Tin		
AEC-Q200	No		
Component Weight	58.97 mg		
Notes	P and R dimensions represents the minimum solderable area of the termination surface entirely below cutout (if one is present).		

Specifications				
Capacitance	.47 uF			
Capacitance Tolerance	10%			
Voltage DC	35 VDC (85C), 23.45 VDC (125C)			
Temperature Range	-55/+125°C			
Rated Temperature	85°C			
Dissipation Factor	4% 120Hz 25C			
Failure Rate	N/A			
Resistance	14 Ohms (100kHz 25C)			
Ripple Current	73 mA (rms, 100kHz 25C)			
Leakage Current	0.5 uA (5min 25°C)			
Testing and Reliability	Standard Testing Only			

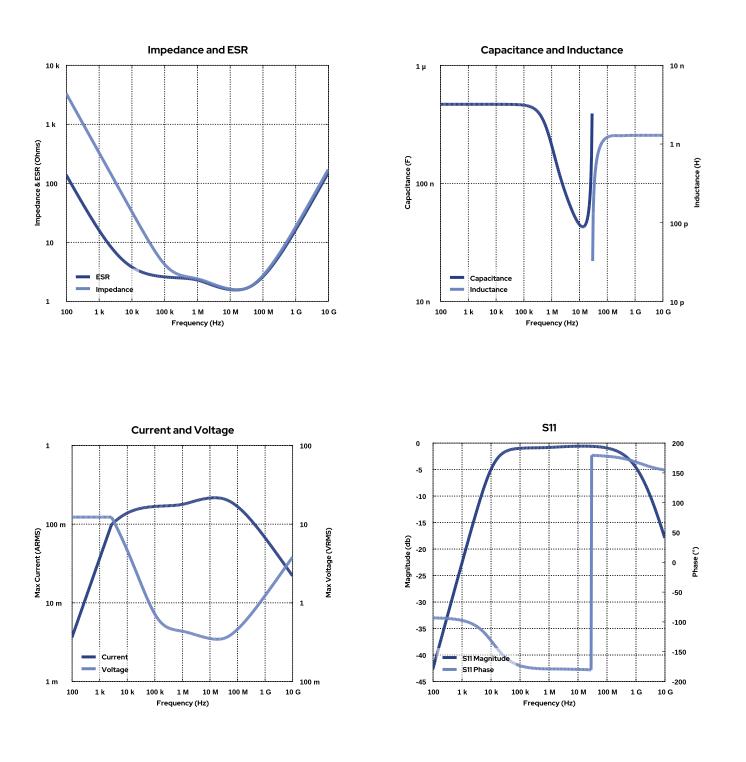
Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.



T493A474K035AT6110 T493 HRA, Tantalum, MnO2 Tantalum, HRA, .47 uF, 10%, 35 VDC, SMD, MnO2, Molded, High Reliability, N/A, 14 Ohms, 3216, Height Max = 1.8mm

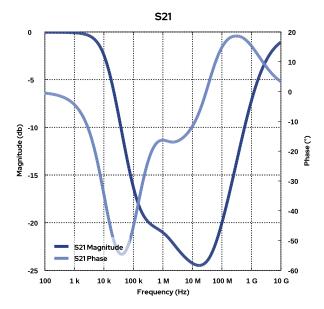
Simulations

For the complete simulation environment please visit K-SIM.





T493A474K035AT6110 T493 HRA, Tantalum, MnO2 Tantalum, HRA, .47 uF, 10%, 35 VDC, SMD, MnO2, Molded, High Reliability, N/A, 14 Ohms, 3216, Height Max = 1.8mm





T493A474K035AT6110

T493 HRA, Tantalum, MnO2 Tantalum, HRA, .47 uF, 10%, 35 VDC, SMD, MnO2, Molded, High Reliability, N/A, 14 Ohms, 3216, Height Max = 1.8mm

These are simulations.

This is not a specification!

The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

The responses shown do not represent a specified or implied maximum capability of the device for all applications.

- The ESR used for ripple "Ripple Current/Voltage vs. Frequency" plots is the ESR at ambient temperature.
- The ESR in the "Temperature Rise vs. Ripple Current" plots is adjusted to each incremental temperature rise before the power and ripple current is calculated.
- The effects shown herein are based on measured data from a multiple part sample of the parts in question.
- Ripple capability of this device will be factored by thermal resistance (Rth) created by circuit traces (addi affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance. The peak voltages generated in the "Temperature Rise vs. Combined Ripple Currents" plot are calculated for each frequency and are not combined with voltages generated at any other
- harmonics.
- Please consult with the catalog or field applications engineer for maximum capability of the device in specific applications.

All product information and data (collectively, the "Information") are subject to change without notice.

KEMET K-SIM is designed to simulate behavior of components with respect to frequency, ambient temperature, and DC bias levels. The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation effects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

All Information given herein is believed to be accurate and reliable, but is presented without guarantee, warranty, or responsibility of any kind, expressed or implied. Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute – and we specifically disclaim – any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

If you have any questions please contact K-SIM.